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# BGM681L11 GPS Front-End with high Out-of-Band Attenuation

## Small Signal Discretes



Never stop thinking

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#### Oct. 2008

#### Revision History: GPS Front-End with high Out-of-Band Attenuation, Rev.2.2

Previous Version: 2008-10-02, Rev. 2.1

Page	Subjects (major changes since last revision)						
4	Updated Figure 1						
8	Updated Figure 2						
7	Updated Footnote 3)						
7	Updated Gain Switch Control Voltage Max. value						
5	Updated Product Description						



#### GPS Front-End with high Out-of-Band Attenuation

BGM681L11

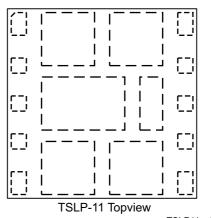
## 1 GPS Front-End with high Out-of-Band Attenuation

#### Features

- Operating frequency: 1575.42 +/- 10 MHz
- High Gain: 17.5 dB
- Low Noise Figure: 1.9 dB
- Power down function
- Input compression point in GSM bands: 24 dBm
- Input compression point in WLAN bands: 24 dBm
- Supply voltage: 2.4 V to 3.6 V
- Tiny TSLP-11-1 leadless package
- RF internally pre-matched
- RF output internally matched to 50  $\Omega$
- RF input to antenna has 1 kV HBM ESD protection
- Minimum need of only 5 external SMD parts
- Attenuation in GSM & UMTS bands > 50 dB
- RoHS compliant package

## Application

• 1575.42 MHz GPS



TSLP11\_v2.vsd

TSLP-11-1 Topview (2.5 x 2.5 x 0.6 mm<sup>3</sup>)



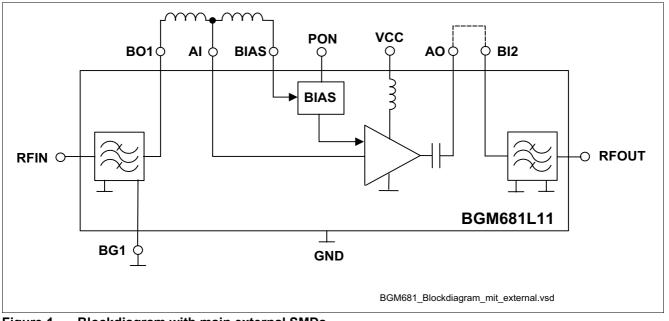


Figure 1 Blockdiagram with main external SMDs



#### Description

## 2 Description

The BGM681L11 is a combination of a low-insertion-loss input filter with Infineon's high performance low noise amplifier BGA615L7 and a high-attenuation output filter for Global Positioning System (GPS) applications. Through the low insertion loss of the filters, the BGM681L11 provides 17.5 dB gain, 1.9 dB noise figure and high linearity performance. In addition BGM681 provides very high out-of-band attenuation in conjunction with a high input compression point. Its current consumption is as low as 5.6 mA. It operates over the 2.4 V to 3.6 V supply voltage range.

Туре	Package	Marking
BGM681L11	TSLP-11-1	M681

#### **Pin Definition and Function**

#### Table 1 Pin Definition and Function

Pin No.	Symbol	Function		
1	BI2	Output-Filter Input		
2	PON	Power On		
3	VCC	Power Supply		
4	AO	LNA Output		
5	RFIN	RF Input		
6	BG1	Input-Filter GND		
7	BO1	Input-Filter Output		
8	AI	LNA Input		
9	BIAS	BIAS		
10	RFOUT	RF Output		
11	GND	Package Middle Island		

#### Maximum Ratings

#### Table 2Maximum Ratings

Parameter <sup>1)</sup>	Symbol	Value	Unit
Voltage at pin BI2 to GND	V <sub>BI2</sub>	-1010	V
Voltage at pin PON to GND	V <sub>PON</sub>	-0.33.6	V
Voltage at pin VCC to GND	V <sub>CC</sub>	-0.33.6	V
Voltage at pin AO to GND	V <sub>AO</sub>	-0.3V <sub>CC</sub> + 0.3	V
Voltage at pin RFIN to GND	V <sub>RFIN</sub>	-1010	V
Voltage at pin BG1 to GND	V <sub>BG1</sub>	-1010	V
Voltage at pin B01 to GND	V <sub>BO1</sub>	-1010	V
Voltage at pin AI to GND	V <sub>AI</sub>	-0.30.9	V
Voltage at pin BIAS to GND	V <sub>BIAS</sub>	-0.30.9	V
Voltage at pin RFOUT to GND	V <sub>RFOUT</sub>	-1010	V
Current into pin VCC	I <sub>VCC</sub>	25	mA
RF input power @ 1575 MHz	P <sub>IN</sub>	10	dBm
Total power dissipation	P <sub>tot</sub>	90	mW



#### Description

#### Table 2Maximum Ratings (cont'd)

Parameter <sup>1)</sup>	Symbol	Value	Unit
Junction temperature	TJ	150	°C
Ambient temperature range	T <sub>A</sub>	-30 85	°C
Storage temperature range	$T_{\rm STG}$	-65 150	°C
ESD capability (HBM: JESD22A-114) of all pins except pins 6, 7 and 10	V <sub>ESD1</sub>	1000	V
ESD capability (HBM: JESD22A-114) of pins 7 and 10, with pin 6 and GND Middle Island pin 11 tied together	V <sub>ESD2</sub>	500	V

1) All voltages refer pin-to-pin.



**Electrical Characteristics** 

## 3 Electrical Characteristics

For out of band P 1dB Compression Point and IP3, please refer to Infineon Application Note AN162

Parameter	Symbol	- 25 C, V <sub>CC</sub> - 2.6 V, V <sub>PON,ON</sub> - Values			Unit	Note / Test Condition
		Min.	Тур.	Max.		
Supply Voltage	V <sub>CC</sub>	2.4	2.8	3.6	V	
Supply Current	I <sub>CC</sub>	-	5.6	6.3	mA	ON-Mode
		-	0.2	3	μA	OFF-Mode
Gain Switch Control Voltage	V <sub>pon</sub>	2.1	-	3.6	V	ON-Mode
		0	-	0.5	V	OFF-Mode
Gain Switch Control Current	I <sub>pon</sub>	-	1.5	3.0	μA	ON-Mode
	P	-	0	1	μA	OFF-Mode
Power Gain settling time <sup>2)</sup>	t <sub>S</sub>	-	5	-	μs	OFF- to ON-Mode
		-	5	-	μs	ON- to OFF-mode
Passband Parameters @ f = 1575.42 MHz						
Insertion Power Gain	$ S_{21} ^2$	15	17.5	19	dB	High-Gain Mode
Noise Figure <sup>3)</sup>	NF	-	1.9	-	dB	Z <sub>S</sub> = 50 Ω
Input Return Loss	<i>RL</i> <sub>in</sub>	-	10	-	dB	
Output Return Loss	<i>RL</i> <sub>out</sub>	-	10	-	dB	
Reverse Isolation	$1/ S_{12} ^2$	-	25	-	dB	
Inband Input 3rd Order Intercept Point	IIP <sub>3</sub>	-	-3	-	dBm	$f_1 = 1575 \text{ MHz}, f_2 = f_1 + f_1$ 1 MHz
Inband Input 1 dB compression point	IP <sub>1dB</sub>	-	-10	-	dBm	<i>f</i> = 1575 MHz
Stopband Parameters						
Attenuation <sup>4)</sup>	Attn <sub>900M</sub>	-	60	-	dB	<i>f</i> = 806 MHz - 928 MHz
Attenuation <sup>4)</sup>	Attn <sub>1800M</sub>	-	50	-	dB	<i>f</i> = 1710 MHz - 1980 Mł
Attenuation <sup>4)</sup>	Attn <sub>2400M</sub>	-	40	-	dB	<i>f</i> = 2400 MHz - 2500 MI
Attenuation <sup>4)</sup>	Attn <sub>&gt;2500M</sub>	-	30	-	dB	<i>f</i> = 2500 MHz - 6000 MI
Stability	k	-	>1	-		<i>f</i> = 10 MHz - 10 GHz

Table 3 Electrical Characteristics:  $T_A = 25 \text{ °C}$ ,  $V_{CC} = 2.8 \text{ V}$ ,  $V_{PON,ON} = 2.8 \text{ V}$ ,  $V_{PON,OFF} = 0 \text{ V}^{1)}$ 

1) Measured on BGM681L11 application board including PCB losses (unless noted otherwise)

2) Within 1 dB of the final gain

3) PCB losses subtracted, verified on AQL base

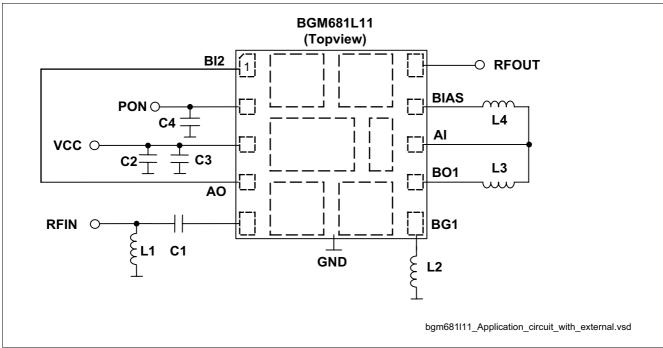
4) Due to high in-band to out-of-band dynamic range, the out-of-band attenuation value depends strongly on the grounding of the PCB



**Application Information** 

## 4 Application Information

### 4.1 Application Circuit



#### Figure 2 Application Circuit with external components

	Bill of Materials							
Name	Value	Package	Manufacturer	Function				
C1	2.2 pF	0402	Various	Input matching				
C2	2.2 nF	0402	Various	Supply voltage filtering (optional)				
C3	100 pF	0402	Various	Supply voltage filtering				
C4	10 pF	0402	Various	Control voltage filtering				
L1	4.7 nH	0402	muRata LQW15A	Input matching / ESD protection				
L2	3.3 nH	0402	muRata LQW15A Attenuation and Linearit improvement at 1710 - 7 (optional)					
L3	2.9 nH	0402	muRata LQW15A	Input matching				
L4	68 nH	0402	muRata LQW15A	Bias				
N1	BGM681L11	TSLP-11-1	Infineon	GPS FE System				

#### Table 4 Bill of Materials



**Application Information** 

### 4.2 Application Board

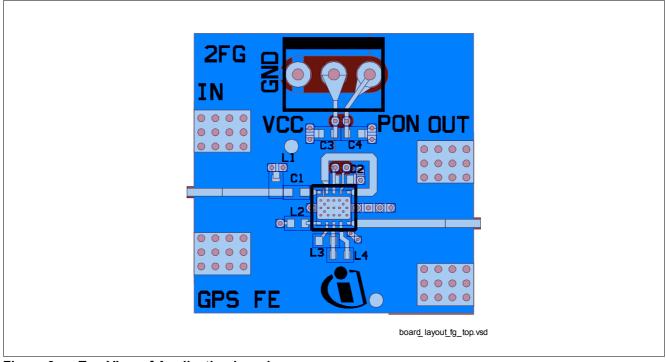


Figure 3 Top View of Application board

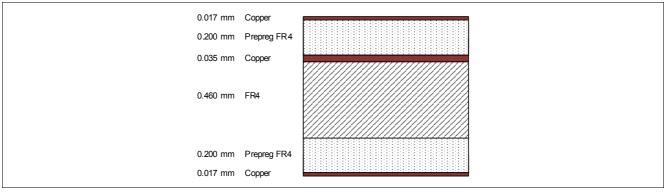


Figure 4 Cross section View of Application board



#### BGM681L11

**Package Information** 

## 5 Package Information

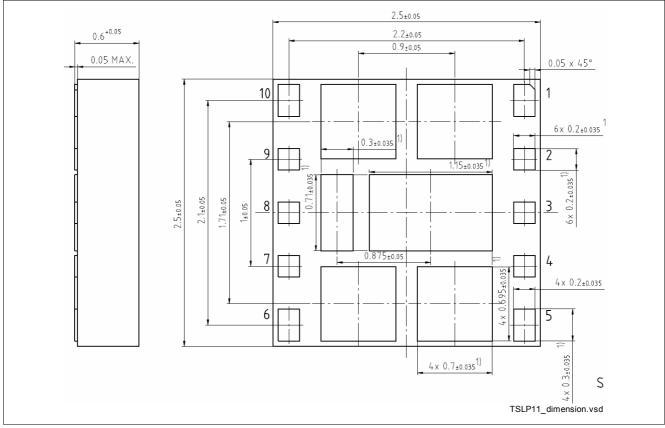


Figure 5 TSLP-11-1 Side View and Bottom View



#### BGM681L11

#### **Package Information**

